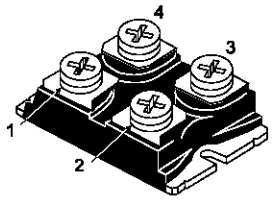
SGS-THOMSON MICROELECTRONICS

BUT30V

NPN TRANSISTOR POWER MODULE

- NPN TRANSISTOR
- HIGH CURRENT POWER BIPOLAR MODULE
- VERY LOW R_{th} JUNCTION CASE
- SPECIFIED ACCIDENTAL OVERLOAD AREAS
- ISOLATED CASE (2500V RMS)
- EASY TO MOUNT
- LOW INTERNAL PARASITIC INDUCTANCE

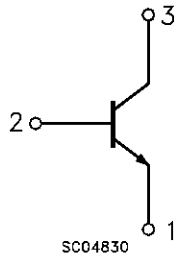
APPLICATIONS:
- MOTOR CONTROL
- SMPS & UPS
- WELDING EQUIPMENT



Pin 4 not connected

ISOTOP

INTERNAL SCHEMATIC DIAGRAM



ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
V_{CEV}	Collector-Emitter Voltage (V_{BE} = -5 V)	200	V
$V_{CEO(sus)}$	Collector-Emitter Voltage (I_B = 0)	125	V
V_{EBO}	Emitter-Base Voltage (I_C = 0)	7	V
I_C	Collector Current	100	A
I_{CM}	Collector Peak Current (t_p = 10 ms)	150	A
I_B	Base Current	20	A
I_{BM}	Base Peak Current (t_p = 10 ms)	30	A
P_{tot}	Total Dissipation at T_c = 25 °C	250	W
T_{stg}	Storage Temperature	-55 to 150	°C
T_j	Max. Operating Junction Temperature	150	°C
V_{ISO}	Insulation Withstand Voltage (AC-RMS)	2500	V

THERMAL DATA

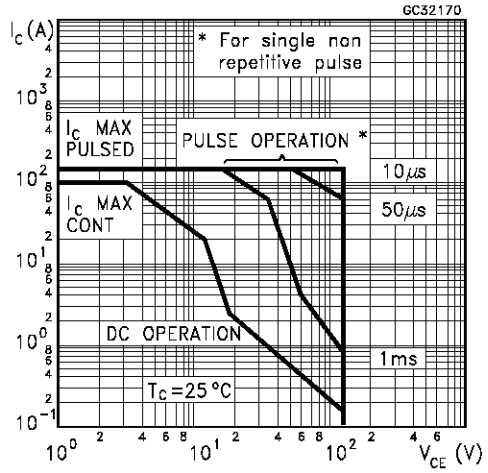
$R_{thj\text{-}case}$	Thermal Resistance Junction-case	Max	0.5	°C/W
$R_{thc\text{-}h}$	Thermal Resistance Case-heatsink With Conductive Grease Applied	Max	0.05	°C/W

ELECTRICAL CHARACTERISTICS (T_{case} = 25 °C unless otherwise specified)

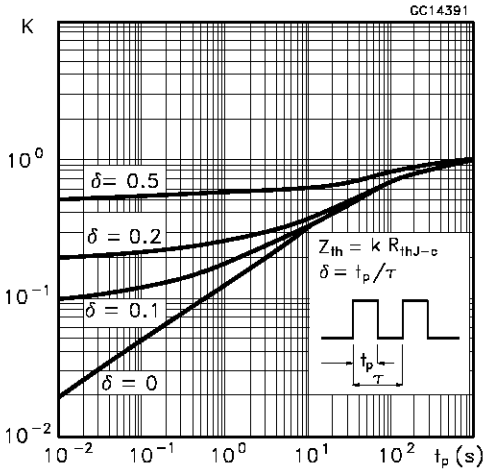
Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
I_{CER}	Collector Cut-off Current (R_{BE} = 5 Ω)	$V_{CE} = V_{CEV}$ $V_{CE} = V_{CEV}$ T_j = 100 °C			1 5	mA mA
I_{CEV}	Collector Cut-off Current (V_{BE} = -5V)	$V_{CE} = V_{CEV}$ $V_{CE} = V_{CEV}$ T_j = 100 °C			1 4	mA mA
I_{EBO}	Emitter Cut-off Current (I_C = 0)	V_{EB} = 5 V			1	mA
$V_{CEO(SUS)}$*	Collector-Emitter Sustaining Voltage	I_C = 0.2 A L = 25 mH V_{clamp} = 125 V	125			V
h_{FE}*	DC Current Gain	I_C = 100 A V_{CE} = 5 V		27		
$V_{CE(sat)}$*	Collector-Emitter Saturation Voltage	I_C = 50 A I_B = 2.5 A I_C = 50 A I_B = 2.5 A T_j = 100 °C I_C = 100 A I_B = 10 A I_C = 100 A I_B = 10 A T_j = 100 °C		0.45 0.55 0.7 0.9	0.9 1.2 0.9 1.5	V V V V
$V_{BE(sat)}$*	Base-Emitter Saturation Voltage	I_C = 50 A I_B = 2.5 A I_C = 50 A I_B = 2.5 A T_j = 100 °C I_C = 100 A I_B = 10 A I_C = 100 A I_B = 10 A T_j = 100 °C		1.15 1.1 1.45 1.55	1.4 1.4 1.8 1.9	V V V V
di_C/dt	Rate of Rise of On-state Collector	V_{CC} = 300 V R_C = 0 t_p = 3 µs I_{B1} = 15 A T_j = 100 °C	270	350		A/µs
V_{CE}(3 µs)•	Collector-Emitter Dynamic Voltage	V_{CC} = 300 V R_C = 1 Ω I_{B1} = 15 A T_j = 100 °C		2.7	3.5	V
V_{CE}(5 µs)•	Collector-Emitter Dynamic Voltage	V_{CC} = 300 V R_C = 1 Ω I_{B1} = 15 A T_j = 100 °C		2	2.5	V
t_s t_f t_c	Storage Time Fall Time Cross-over Time	I_C = 100 A V_{CC} = 90 V V_{BB} = -5 V R_{BB} = 0.47 Ω V_{clamp} = 125 V I_{B1} = 10 A L = 45 µH T_j = 100 °C		1 0.1 0.2	2 0.2 0.35	µs µs µs
V_{CEW}	Maximum Collector Emitter Voltage Without Snubber	I_{CWoff} = 150 A I_{B1} = 10 A V_{BB} = -5 V V_{CC} = 90 V L = 30 µH R_{BB} = 0.5 Ω T_j = 125 °C	125			V

∗ Pulsed: Pulse duration = 300 µs, duty cycle 1.5 %

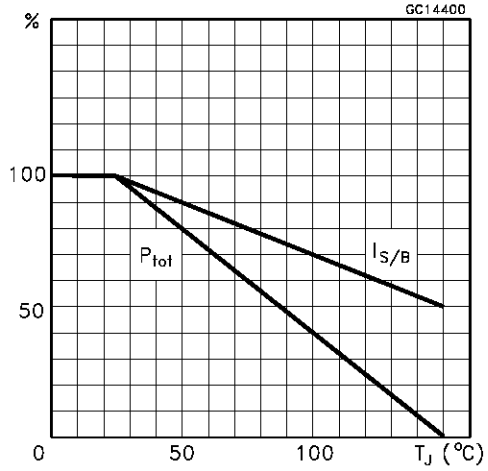
Safe Operating Areas



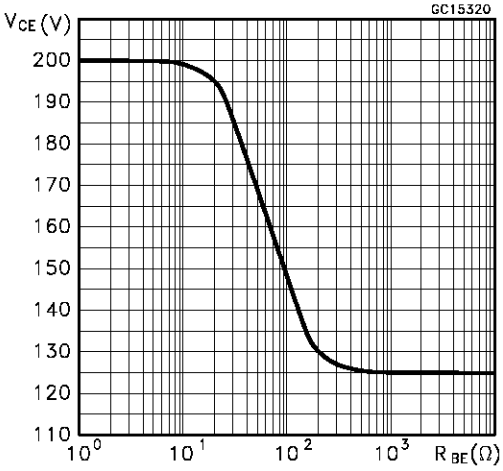
Thermal Impedance



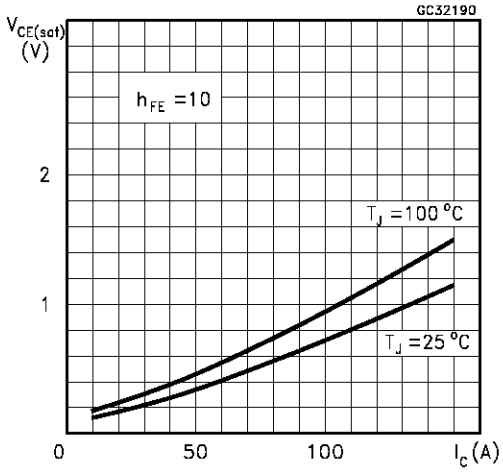
Derating Curve



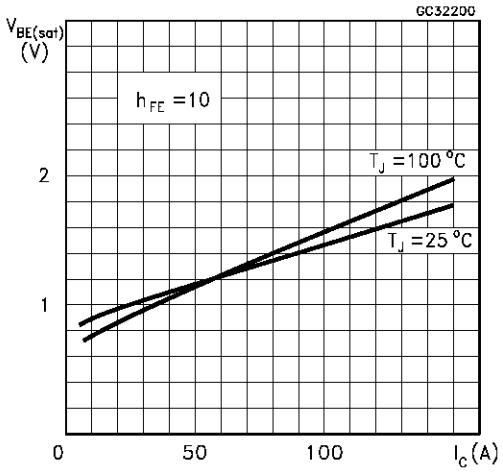
Collector-emitter Voltage Versus base-emitter Resistance



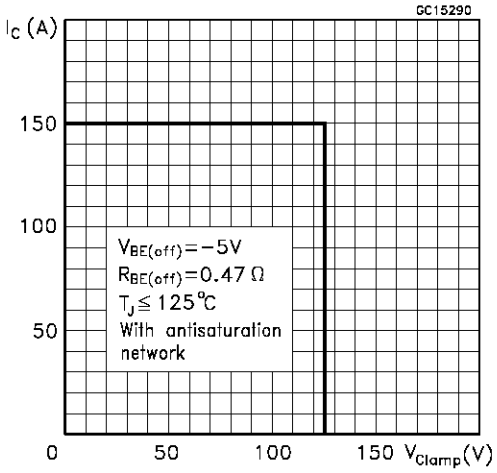
Collector Emitter Saturation Voltage



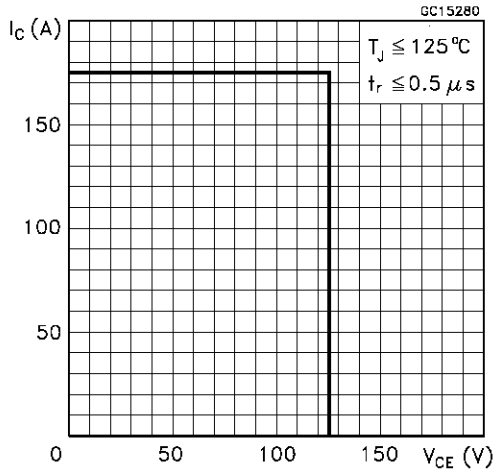
Base-Emitter Saturation Voltage



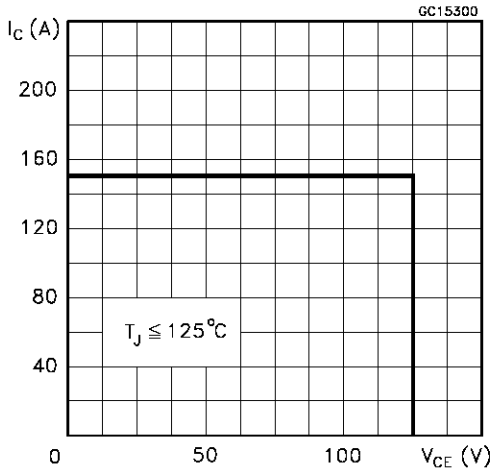
Reverse Biased SOA



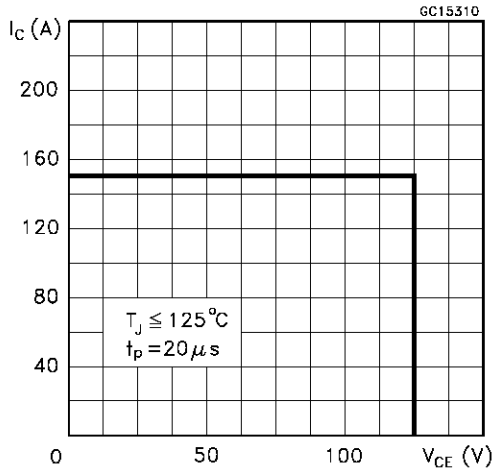
Foward Biased SOA



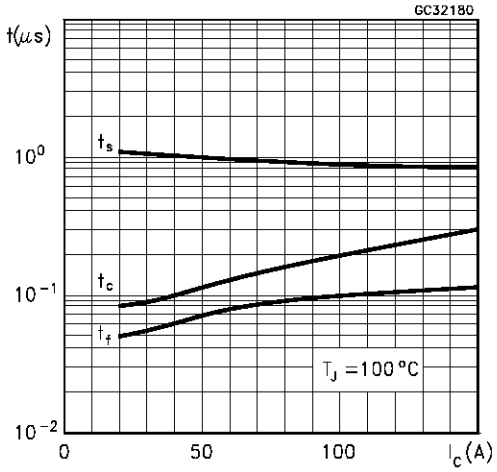
Reverse Biased AOA



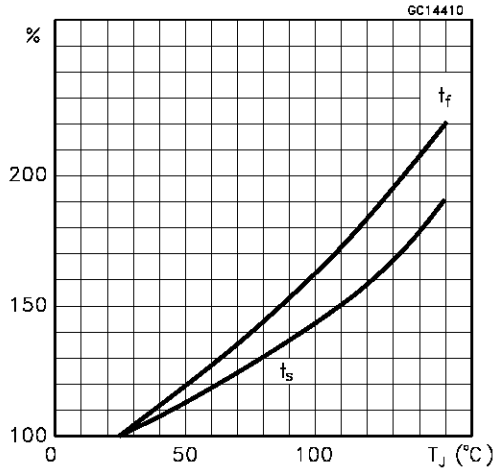
Forward Biased AOA



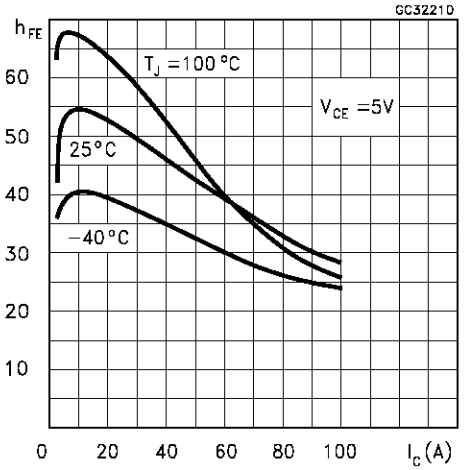
Switching Times Inductive Load



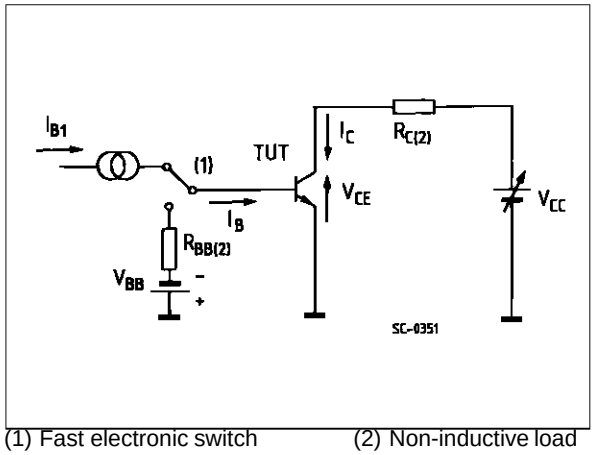
Switching Times Inductive Load Versus Temperature



Dc Current Gain

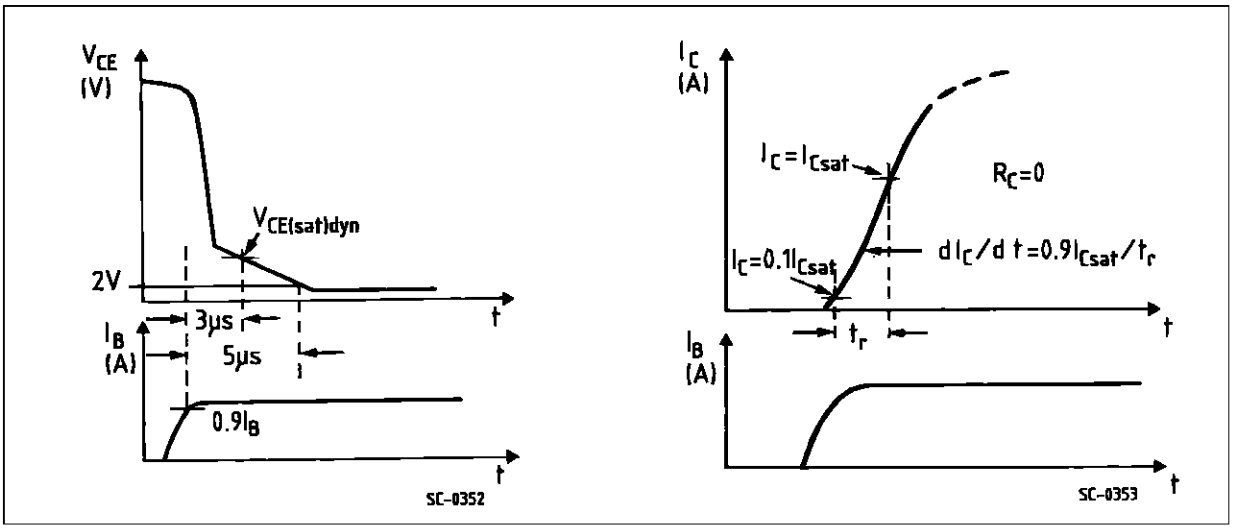


Turn-on Switching Test Circuit

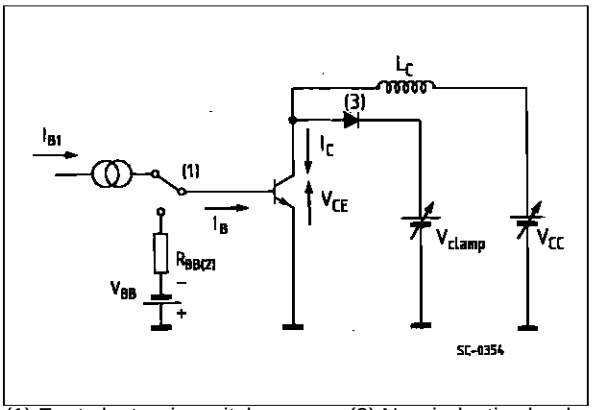


(1) Fast electronic switch (2) Non-inductive load

Turn-on Switching Waveforms

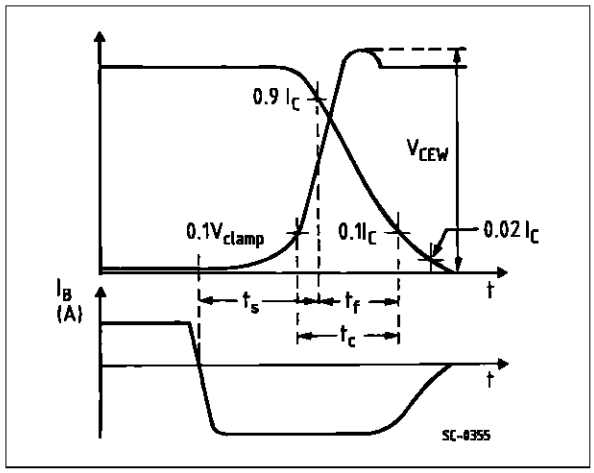


Turn-off Switching Test Circuit



(1) Fast electronic switch (2) Non-inductive load
(3) Fast recovery rectifier

Turn-off Switching Waveforms



ISOTOP MECHANICAL DATA

DIM.	mm			inch		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
A	11.8		12.2	0.466		0.480
B	8.9		9.1	0.350		0.358
C	1.95		2.05	0.076		0.080
D	0.75		0.85	0.029		0.033
E	12.6		12.8	0.496		0.503
F	25.15		25.5	0.990		1.003
G	31.5		31.7	1.240		1.248
H	4			0.157		
J	4.1		4.3	0.161		0.169
K	14.9		15.1	0.586		0.594
L	30.1		30.3	1.185		1.193
M	37.8		38.2	1.488		1.503
N	4			0.157		
O	7.8		8.2	0.307		0.322